061006T4ICT
ICT TECNICIAN LEVEL 6
IT/OS/ICT/CC/01
APPLY BASIC ELECTRONICS
NOV/DEC 2023


# TVET CURRICULUM DEVELOPMENT, ASSESSMENT AND CERTIFICATION COUNCIL (TVET CDACC) 

## WRITTEN ASSESSMENT

## Time: 3 Hours

## INSTRUCTIONS TO CANDIDATES

1. This paper has TWO sections A and B Attempt questions in each section as per instructions given in the section.
2. You are provided with a separate answer booklet.
3. Marks for each question are indicated in the brackets.
4. Do not write on the question paper

This paper consists of 4 printed pages
Candidates should check the question paper to ascertain that all pages are printed as indicated and that no questions are missing.

## SECTION A: 40 MARKS

## Answer ALL questions in this section.

1. List any FOUR electronic components and their functions.
2. State TWO types of switches?
3. Define the following terms as used in electronics
i. Electric current
ii. Potential difference
iii. Series circuit
iv. Parallel circuit
4. Define the term nanoelectronics and state one way that it has affected the design and manufacturing of electronic devices.
5. State ohm's law.
6. If the resistance of an electric iron is $50 \Omega$ and a current of 3.2 A flows through the resistance. What is the voltage?
7. Draw a labelled, schematic diagram of an electric circuit comprising of a cell, a resistor, an ammeter, a voltmeter and a closed switch
8. Outline any FIVE advantages and FOUR disadvantages of semiconductor over other devices?
9. Outline any TWO differences between intrinsic and extrinsic semiconductors.

## SECTION B: 60 MARKS

## Answer any THREE questions in this section.

10. 

a) Differentiate between the following as used in computers.
i. Dynamic RAM (DRAM) and static RAM (SRAM).
ii. Main Memory and cache memory.
b) With the aid of a diagram outline the structure of magnetic disk. Showing the track sectors, disk sectors and tracks.
c) Discuss any SIX challenges of emerging trends in electronic manufacturing.
11.
a) Outline FOUR differences between N-type and P-type semiconductors
b) Explain the following terms as used in Bipolar transistor configuration
i. Common Base Configuration
ii. Common Emitter Configuration
iii. Common Collector Configuration
c) With aid of a sketch, outline the configurations mentioned in 5 b above PN junction diode showing both the input signaland output.
12.
a) List FOUR types of number systems used in computers together with their base.
b) Convert the following number systems to their equivalent as indicated in each question

Binary to Decimal
i. $\quad 1011_{2}$
ii. $\quad 10110_{2}$

Octal to Decimal
i. $\quad 542_{8}$
ii. $\quad 3458$

Hexadecimal to decimal
i. 3 A 4 .
ii. (1F.01B) ${ }_{16}$
(2 Marks)
Decimal to hexadecimal equivalent
i. $\quad 245_{10}$ to hexadecimal

Binary fraction to hexadecimal

$$
\text { i. }(001100101.110111)_{2}
$$

13. 

a) Differentiate between the following terms as used in computer storage:
i. Zip disk and Flash disk;
ii. Primary and secondary storage.
b) Explain FOUR Types of compact disks.
c) Discuss FOUR types of Read Only Memory.

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